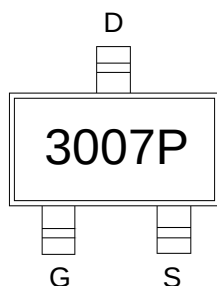


Features

- Green Device Available
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

Application

- Battery protection
- Load switch
- Power management

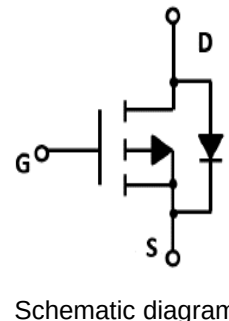
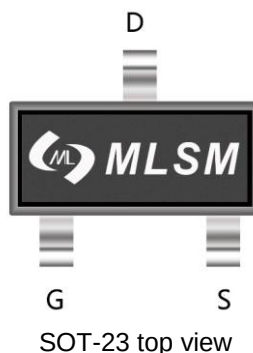


3007P: Device code

Marking and pin assignment

Product Summary

V_{DS}	$R_{DS(ON)}$ TYP	I_D
-30V	20mΩ@-10V	-7A
	27mΩ@-4.5V	



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
--------	-----------	--------	------

Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	-30	V
V_{GS}	Gate-Source Voltage	±20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	Tc=25°C -7	A

Mounted on Large Heat Sink

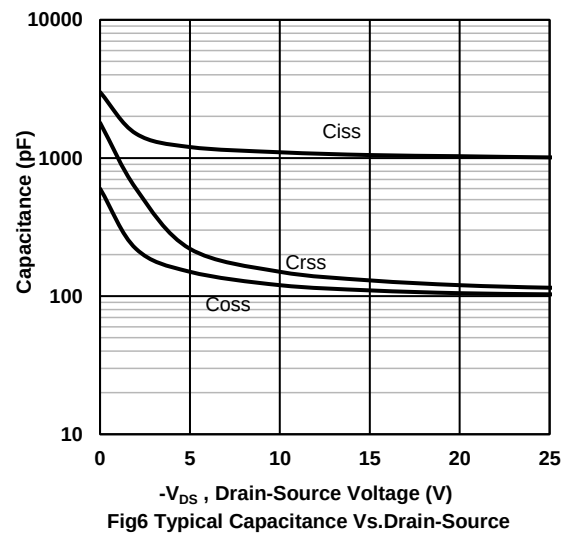
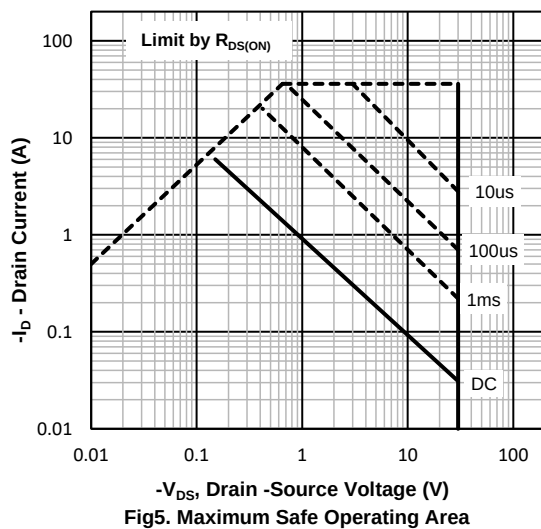
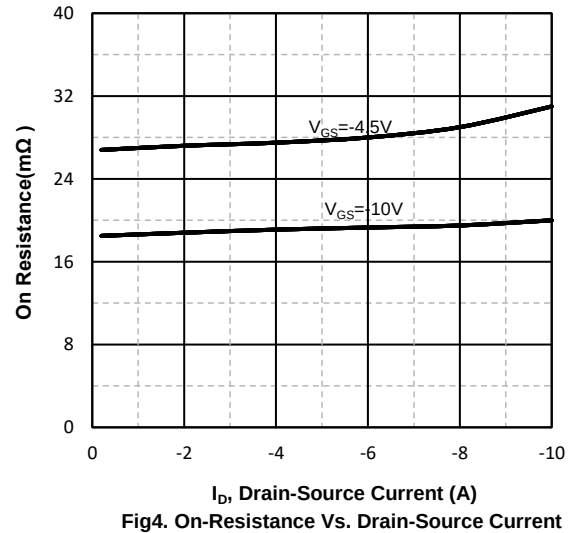
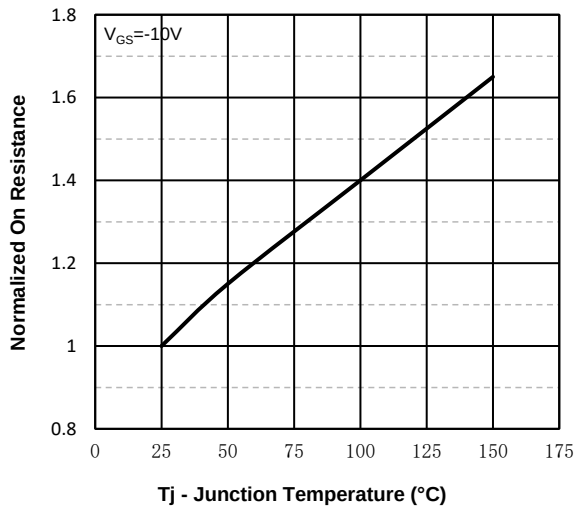
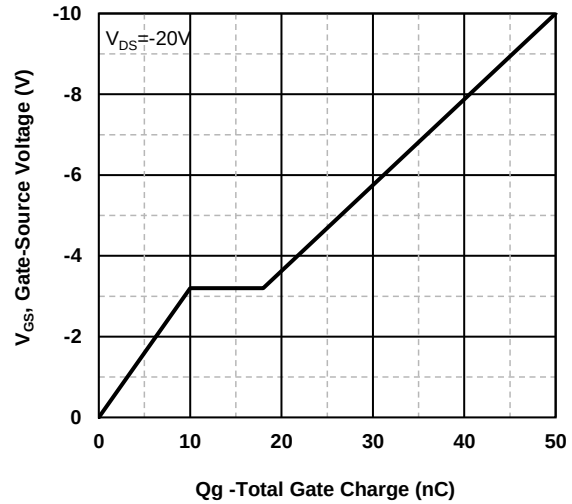
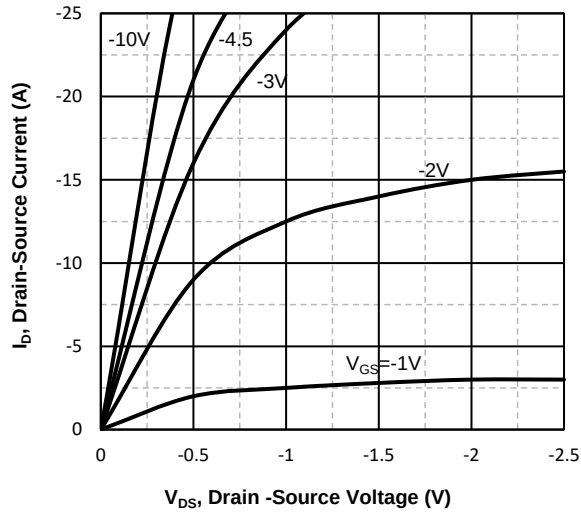
I_{DM}	Pulse Drain Current Tested	Tc=25°C -36	A
I_D	Continuous Drain Current	Tc=25°C -7	A
P_D	Maximum Power Dissipation	Tc=25°C 2.3	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	45	°C/W

Ordering Information (Example)

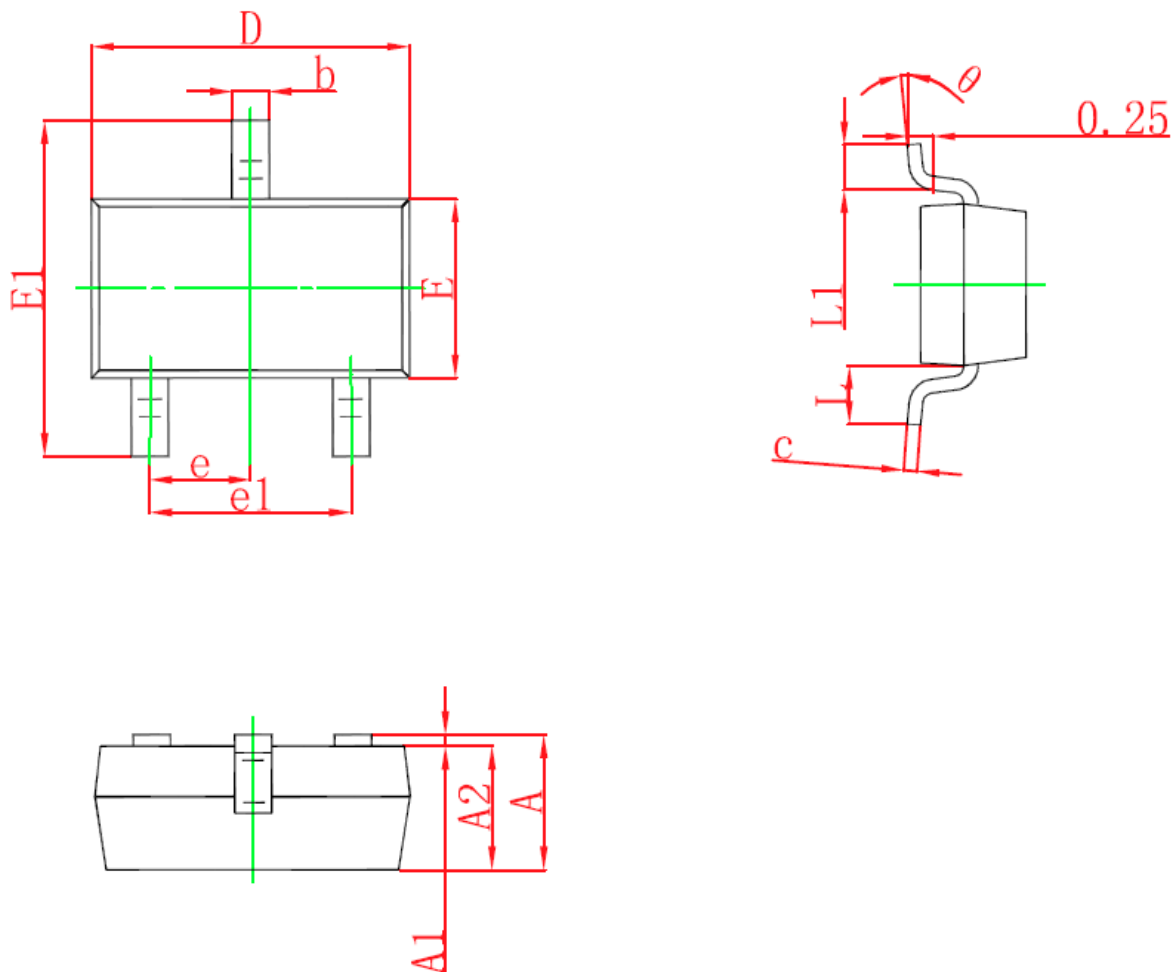
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLS3007P	SOT-23	3007P	3,000	45,000	180,000	7"reel

Electrical Characteristics (TJ=25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250μA	-30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-30V, V _{GS} =0V	--	--	-1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250μA	-1.0	--	-2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =-10V, I _D =-7A	--	20	30	mΩ
		V _{GS} =-4.5V, I _D =-5A	--	27	45	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =-15V, V _{GS} =0V, f=1MHz	--	1200	--	pF
C _{OSS}	Output Capacitance		--	155	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	140	--	pF
Q _g	Total Gate Charge	V _{DS} =-15V, I _D =-7A, V _{GS} =-10V	--	52	--	nC
Q _{gs}	Gate Source Charge		--	10	--	nC
Q _{gd}	Gate Drain Charge		--	8.5	--	nC
Switching Characteristics						
t _{d(on)}	Turn-on Delay Time	V _{DS} =-15V, I _D =-1A, V _{GS} =-10V, R _G =6Ω	--	13	--	nS
t _r	Turn-on Rise Time		--	15	--	nS
t _{d(off)}	Turn-Off Delay Time		--	200	--	nS
t _f	Turn-Off Fall Time		--	100	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	Tj=25°C, Is=-7A	--	--	-1.2	V

Typical Operating Characteristics



SOT-23 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°